Lab 7 SRAM

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1. Objective

In this lab, we are introduced to latches and flip flops and to under the difference between the two and their functionalities. Latches and flip flops are the basic elements for storing information and one latch or flip flop can store one bit of information and they are sequential device that will remember the previous value inputs and outputs to compute the next output. To understand how latches and flip flop works, we will create several latches and flip flops using block diagrams and VHDL code then run waveform simulations and observe the behavior of these devices. Also, we will be using what we have learned from Latches and Flip-Flops to build SRAM.

The circuit we will be designing in this lab are:

- a. SR Latch
- b. Control SR Latch
- c. D Latch
- d. Positive Edge Triggered Master Slave D Flip Flop
- e. Negative Edge Triggered Master Slave D Flip Flop
- f. JK Flip Flop
- g. T Flip Flop
- h. SRAM Cell
- i. 16x4 SRAM
- j. 16x32 SRAM

2. SR Latch

2.1 Functionality and Specification

The SR Latch is a basic storage device used to store a binary bit. This latch has two functions which are Set and Reset which are defined by S and R. Below is the characteristic table that describes the behavior of the SR Latch.

s	R	Q	Q'	State
0	0	•		No Change
0	1	0	1	Reset
1	0	1	0	Set
1	1	?	?	Undefined

Based on the characteristic table, when input S and R are 0 there are no change for the output Q and Q' which means whatever the previous outputs were then the current outputs will be the same. When S is 0 and R is 1 then it will conduct the function Reset which resets Q back to 0 and since Q' stands for not Q it will always be the opposite of Q so Q' will be 1. When S is 1 and R is 0 then it will conduct the function Set which sets Q to 1 and Q' will be 0. When both S and R is 1, it is considered as the forbidden input that will put the output in a metastable state where it's undefined.

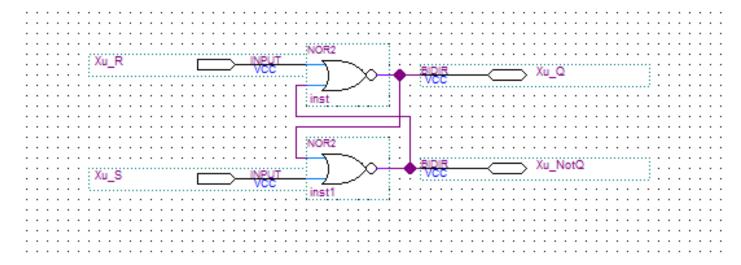


Figure 1: Block diagram for SR Latch.

```
library ieee;
       use ieee.std_logic_1164.all;
       use work.xu_package.all;
 4
     entity SR_Latch is
          port( R, S: in std_logic;
 7
                 Q, NotQ: inout std_logic );
       end SR_Latch;
 9
     marchitecture arch of SR_Latch is
10
          begin
11
     \boldsymbol{\exists}
12
          Q <= R nor NotQ;
13
          NotQ <= 5 nor Q;
       end arch;
14
```

Figure 2: VHDL code for SR Latch.

This is the block diagram and VHDL code for SR Latch, the functionality of these two will be the same. It takes in R and S as inputs and bidirectional outputs which can also function as inputs Q and NotQ. The Boolean function for the outputs will be

$$Q = R \text{ nor Not}Q$$

$$NotQ = S \text{ nor } Q$$

Based on the last lab on VHDL language, we learn that unlike other coding languages which executes line by line, VHDL codes are about to execute parallelly which means all the lines are executed at the same time and alternate changes of the values.

2.2 Simulation

Now we will run the waveform simulation for both block diagram and VHDL code for SR Latch and compare the results that it'll produce.

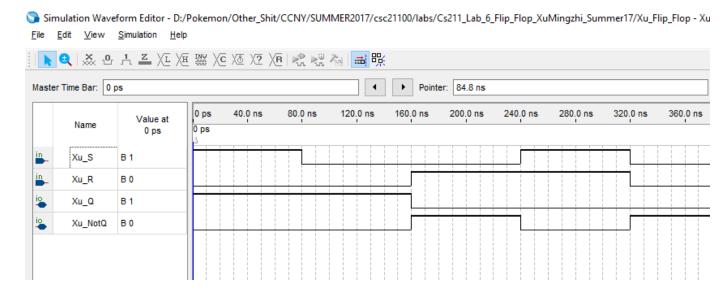


Figure 3: Vector waveform simulation for block diagram of SR Latch.

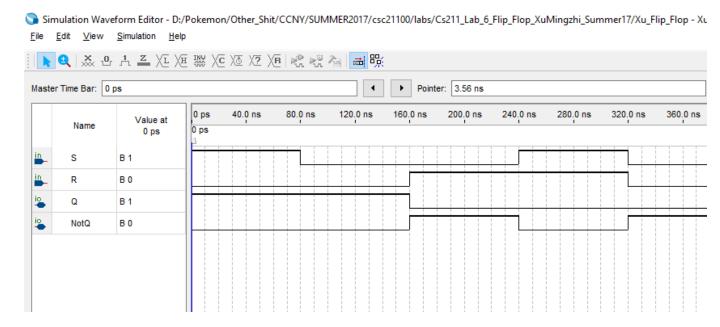


Figure 4: Vector waveform simulation for VHDL code of SR Latch.

We can observe that both simulations produce the same result and it corresponds to characteristic table of SR Latch.

3. Control SR Latch

3.1 Functionality and Specification

The Control SR Latch is similar to the SR Latch that was designed in the last section, but this time it will have an extra input of C which stands for Control which means the user will have control when there will be a state change. Below is the characteristic table of the Control SR Latch.

C	S	R	Q,	Q,'	State
0	X	X	Q	Q'	No Change
1	0	0	Q	Q'	No Change
1	0	1	0	1	Reset
1	1	0	1	0	Set
1	1	1	?	?	Undefined

Based on the characteristic table, when C is 0, no change will be made for whatever S or R are. Which means state changes will on occur when C is 1. When C is 1, it will function the same as SR Latch.

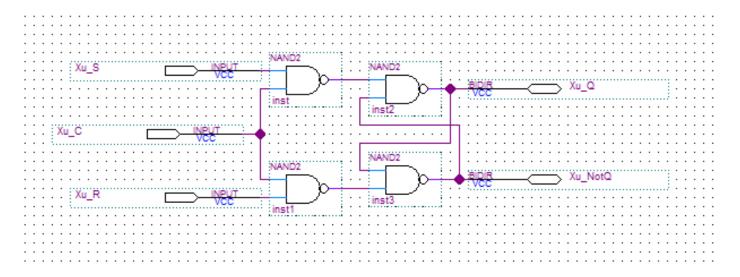


Figure 5: Block diagram of Control SR Latch.

```
library ieee;
 1
 2
       use ieee.std_logic_1164.all;
      use work.Xu_package.all;
 4
 5
     □entity Control_SR_Latch is
 6
          port( C, S, R: in std_logic;
     \boldsymbol{\Xi}
 7
                    NotQ: inOut std_logic );
 8
      end Control_SR_Latch;
 9
     □architecture arch of Control_SR_Latch is
10
11
          begin
12
          Q <= ( S nand C ) nand NotQ;
          NotQ <= ( R nand C ) nand Q;
13
       end arch;
14
```

Figure 6: VHDL code of Control SR Latch.

This is the block diagram and VHDL code for Control SR Latch, this time we will use four

NAND gates to construct the block diagram and the Boolean function are

```
Q = (S \text{ nand } C) \text{ nand Not} Q
```

NotQ = (R nand C) nand Q

3.2 Simulation

Now we will run the waveform simulation for both block diagram and VHDL code for Control SR Latch and compare the results that it'll produce.

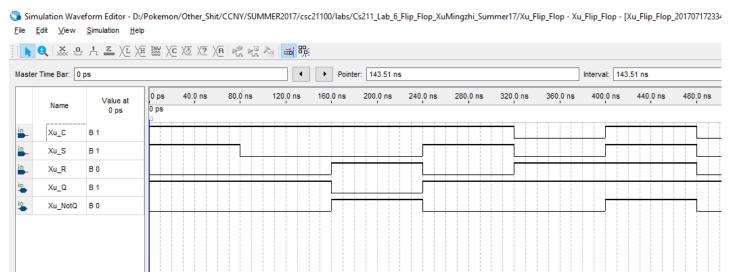


Figure 7: Simulation for block diagram of Control SR Latch.

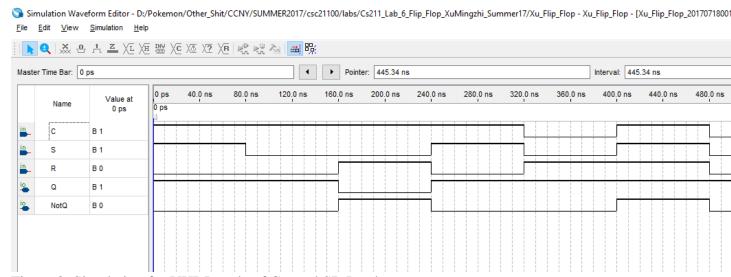


Figure 8: Simulation for VHDL code of Control SR Latch.

We can observe that both simulations produce the same result and it corresponds to characteristic table of Control SR Latch.

4. D Latch

4.1 Functionality and Specification

The D Latch is a modified version of the Control SR Latch which only uses input D to replace Set and Reset. This will make sure that it will never go into metastable state since S and R input will always be opposite of each other due to the use of a NOT gate. Below is the characteristic table of the D Latch.

C	D	Q _n	Q,'	State
0	X	Q	Q'	No Change
1	0	0	1	Reset
1	1	1	0	Set

Based on the characteristic table we can see that the functionality of the D Latch is almost the same the Control SR Latch. When C is 0, there will be no change and will output the previous outputs. When C is 1 and D is 0 it will reset and Q will be 0 and Q' will be 1. When C is 1 and D is 1 it will set Q to 1 and Q' to 0.

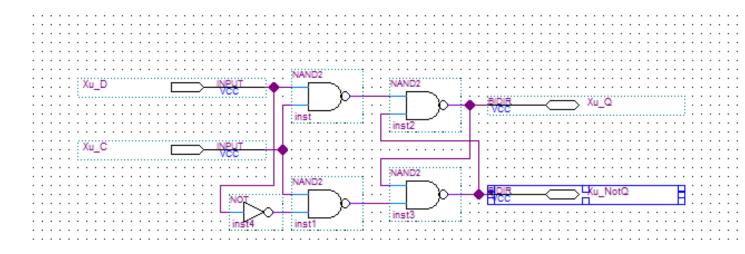


Figure 9: Block diagram of D Latch.

```
66 (7 | ∰ ∰ | № № 10 10 10 1
Nibrary ieee;
      use ieee.std_logic_1164.all;
 3
      use work.Xu_package.all;
 4
 5
     □entity D_Latch is
 6
          port( D, C: in std_logic;
 7
                Q, NotQ: inout std_logic );
 8
      end D_Latch;
 9
     □architecture arch of D_Latch is
10
11
          begin
         Q <= ( D nand C ) nand NotQ;
12
          NotQ <= ( not D nand C ) nand Q;
13
14
      end arch:
```

Figure 10: VHDL code of D Latch.

This is the block diagram and VHDL code for the D Latch. We will use a NOT gate and input D to replace the SR input in the Control SR Latch so there the metastable state will never occur.

The Boolean function will be

```
Q = (D \text{ nand } C) \text{ nand Not}Q
NotQ = (Not D \text{ nand } C) \text{ nand } Q
```

4.2 Simulation

Now we will run the waveform simulation for both block diagram and VHDL code for D Latch and compare the results that it'll produce.

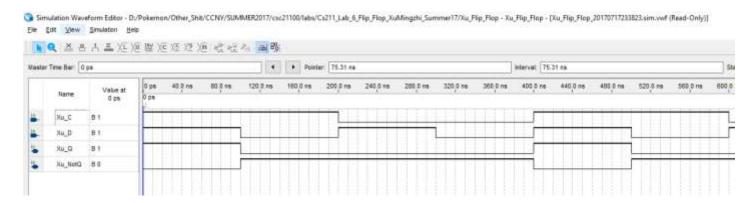


Figure 11: Simulation for block diagram of D Latch.

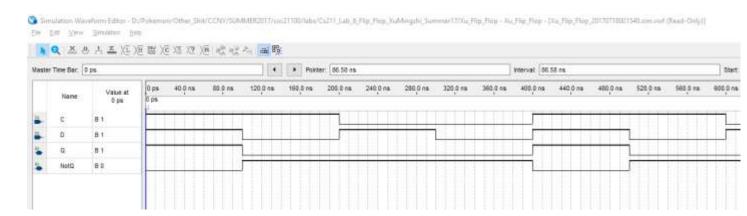


Figure 12: Simulation for VHDL code of D Latch.

We can observe that both simulations produce the same result and it corresponds to characteristic table of D Latch.

5. Positive Edge Triggered Master Slave D Flip Flop

5.1 Functionality and Specification

This is a Positive Edge Triggered Master Slave D Flip Flop, the Master Slave D Flip Flop is made up of two D Latch component. It is different than the D Latch because it triggers the event to change state when the clock signal is going from 0 to 1 or 1 to 0. Since this is a positive edge triggered which means it will change state when the clock signal goes from 0 to 1. Below is the characteristic table for Positive Edge Triggered Master Slave D Flip Flop.

Clk	D	Q	Qnext	Qnext'
0	×	0	0	1
0	×	1	1	0
1	×	0	0	- 1
1	×	1	1	0
	0	×	0	1
	1	×	1	0

Based on the characteristic table we can see that whenever Clock signal is 0 or 1, the D input doesn't affect the output Qnext and will output the previous output Q. When the clock signal goes from 0 to 1, the Qnext will change based on D at that moment.

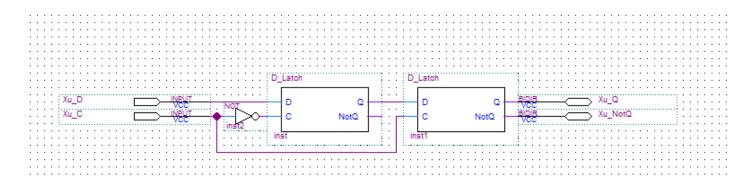


Figure 13: Block diagram for Positive D Flip Flop.

```
● 17 | 課 課 |
      Nibrary ieee;
 1
2345678
      use ieee std_logic_1164.all;
      use work.Xu_package.all;
    □entity Pos_DFF is
         port( D, C: in std_logic;
    Q, NotQ: inout std_logic );
      end Pos_DFF;
 9
10
    □architecture arch of Pos_DFF is
11
         signal OutQ1: std_logic;
12
    D_Latch0: D_Latch port map( D, not C, OutQ1, open );
13
14
         D_Latch1: D_Latch port map( OutQ1, C, Q, NotQ );
15
      end arch:
```

Figure 13: VHDL code for Positive D Flip Flop.

This is the block diagram and VHDL code for Positive Edge Triggered Master Slave D Flip Flop. It uses two D Latch as components and for it to have positive edge trigger, the first clock signal will have a NOT gate.

5.2 Simulation

Now we will run the waveform simulation for both block diagram and VHDL code for Positive Edge Triggered Master Slave D Flip Flop and compare the results that it'll produce.

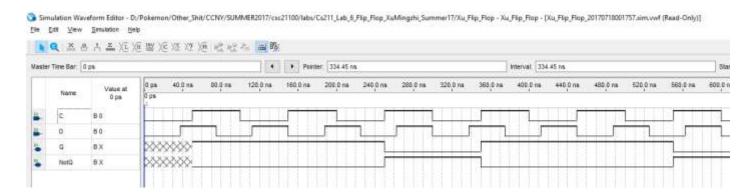


Figure 14: Simulation for block of Positive D Flip Flop.

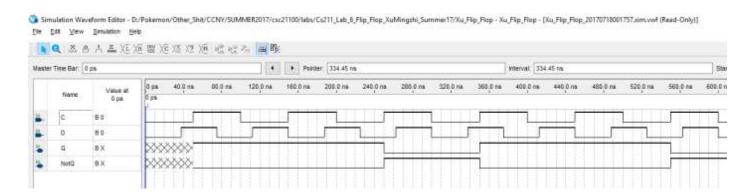


Figure 15: Simulation for VHDL of Positive D Flip Flop.

We can observe that both simulations produce the same result and it corresponds to characteristic table of Positive D Flip Flop.

6. Negative Edge Triggered Master Slave D Flip Flop

6.1 Functionality and Specification

The Negative Edge Triggered Master Slave D Flip Flop functions similarly to the Positive Edge Triggered Master Slave D Flip Flop. The only differences is that it will change state and the clock signal goes from 1 to 0.

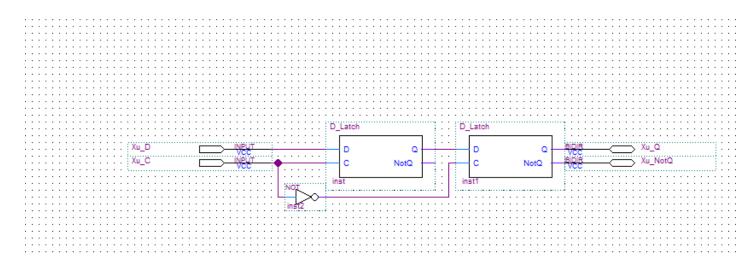


Figure 16: Block diagram for Negative D Flip Flop.

```
● ポー筆 賃
      Nibrary ieee;
1
 2
      use ieee std_logic_1164.all;
 3
      use work.Xu_package.all;
 4
 5
6
7
    □entity Neg_DFF is
         port( D, C: in std_logic;
    Q, NotQ: inout std_logic );
8
      end Neg_DFF;
9
    □architecture arch of Neq_DFF is
10
11
         signal OutQ1: std_logic;
12
    begin
         D_LatchO: D_Latch port map( D, C, OutQ1, open );
13
         D_Latch1: D_Latch port map( OutQ1, not C, Q, NotQ );
14
15
      end arch;
```

Figure 17: VHDL code for Negative D Flip Flop.

This is the block diagram and VHDL code for the Negative Edge Triggered Master Slave D Flip Flop. We can see that it is very similar to the Positive D Flip Flop, but in order for the clock signal to triggered the event to change state from 1 to 0 we will have the NOT gate connect to the clock input in the slave D Latch unlike the Positive D Flip Flop where the NOT gate goes to the Master D Latch clock input.

6.2 Simulation

Now we will run the waveform simulation for both block diagram and VHDL code for Negative Edge Triggered Master Slave D Flip Flop and compare the results that it'll produce

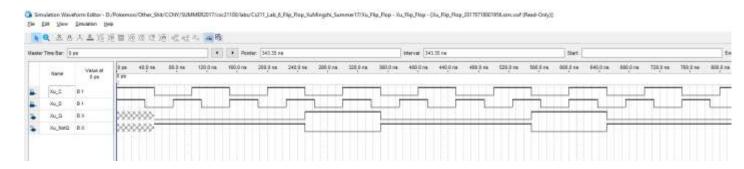


Figure 18: Simulation for block of Negative D Flip Flop.

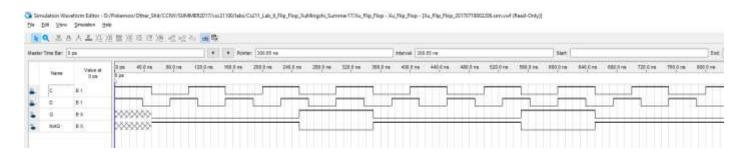


Figure 19: Simulation for VHDL of Negative D Flip Flop.

We can observe that both simulations produce the same result and it corresponds to characteristic table of Negative D Flip Flop.

7. JK Flip Flop

7.1 Functionality and Specification

The JK Flip Flop is very similar to the Control SR Latch but this is a flip flop which means it is a edge triggered device and the JK flip flop uses the Positive D Flip Flop as component. Below is the characteristic table for the JK Flip Flop.

J	K	Q	Qnext	Qnext'
0	0	0	0	1
0	0	1	1	0
0	1	0	0	1
0	1	1	0	1
1	0	0	1	0
1	0	1	1	0
1	1	0	1	0
1	1	1	0	1

Based on the characteristic table we can observe that when both J and K is 0 there will be no change and Qnext will output the previous output Q. When J is 0 and K is 1 Qnext will Reset to 0. When J is 1 and K is 0 Qnext will Set to 1. When both J and K are 0, instead of going into metastable state like the Control SR Latch, it will instead output the NotQ of the previous Q.

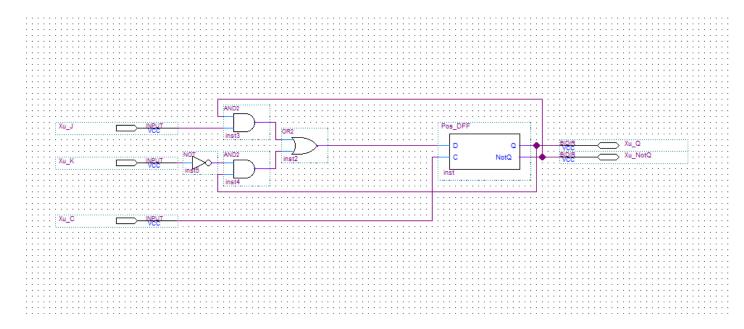


Figure 20: Block diagram of JK Flip Flop.

```
🖷 | 🐽 (計 | 蒜 (蒜 | 🖭 🗗 🖺 | 🕡 🖫 | 🛂 |
      library ieee;
 1
 2
      use ieee std_logic_1164.all;
      use work.Xu_package.all;
 3
 4
 5
     □entity JK_FF is
 6
         port( J, K, C: in std_logic;
    Q, QNot: inout std_logic );
     \blacksquare
 7
 8
     end JK_FF;
 9
     □architecture arch of JK_FF is
10
11
          signal X: std_logic;
12
          begin
     \blacksquare
13
         DFF0: Pos_DFF port map( X, C, Q, QNot );
14
      end arch;
15
```

Figure 21: VHDL code of JK Flip Flop.

7.2 Simulation

Now we will run the waveform simulation for both block diagram and VHDL code for JK Flip Flop and compare the results that it'll produce.

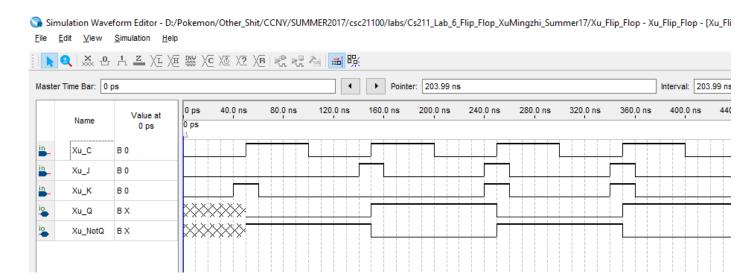


Figure 22: Simulation for block of JK Flip Flop.

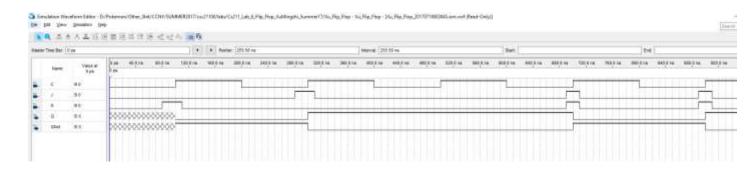


Figure 23: Simulation for VHDL of JK Flip Flop.

We can observe that both simulations produce the same result and it corresponds to characteristic table of JK Flip Flop.

8. T Flip Flop

8.1 Functionality and Specification

The T Flip Flop has the same function as the JK Flip Flop. Below is the characteristic table for the T Flip Flop.

T	Q	Qnext	Qnext'
0	0	0	1
0	1	1	0
1	0	1	0
1	1	0	1

Based on the characteristic table, we can observe that when T is 0 Qnext will output the previous Q. When T is 1 Qnext will output the QNot of the previous Q.

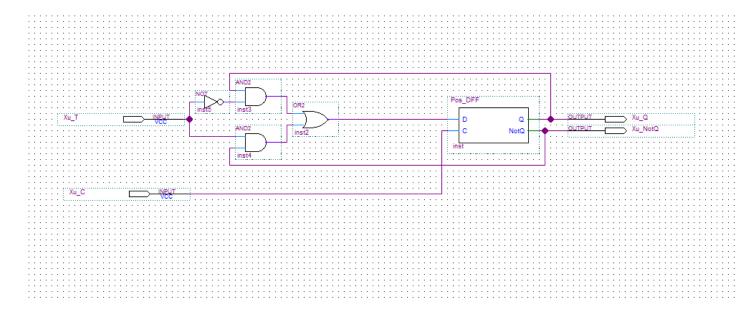


Figure 24: Block diagram of T Flip Flop.

```
曜 | 66 | (7 | 筆 筆 | 🖪 🗗 🖺 |
      library ieee;
1
2
      use ieee.std_logic_1164.all;
      use work.Xu_package.all;
 3
 4
 5
    ⊟entity T_FF is
 6
         port( T, C: in std_logic;
    7
               Q, QNot: out std_logic );
8
      end T_FF;
9
    □architecture arch of T_FF is
10
         signal AND1, AND2, OR1, OutQ1, OutQ2: std_logic;
11
12
    begin
13
         AND1 <= Not T and OutQ1;
14
         AND2 <= T and OutQ2
15
         OR1 <= AND1 or AND2;
         DFF0: Pos_DFF port map( OR1, C, OutQ1, OutQ2 );
16
17
         Q <= OutQ1;
18
         QNot <= OutQ2;
19
      end arch;
```

Figure 25: VHDL code of T Flip Flop.

This is the block diagram and VHDL code for the T Flip Flop. The T Flip Flop functions the same as the JK Flip Flop when both J and K is 1 which will output the QNot of the previous Q.

8.2 Simulation

Now we will run the waveform simulation for both block diagram and VHDL code for T Flip Flop and compare the results that it'll produce.

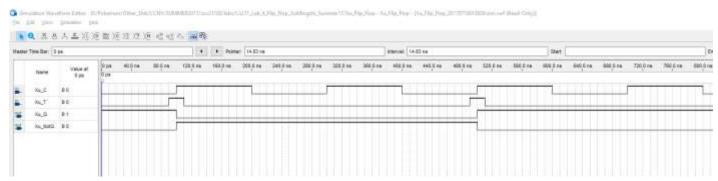


Figure 26: Simulation for block of T Flip Flop.



Figure 27: Simulation for VHDL of T Flip Flop.

We can observe that both simulations produce the same result and it corresponds to characteristic table of T Flip Flop.

9. SRAM Cell

9.1 Functionality and Specification

The single SRAM Cell is made from using a Positive Edge Triggered Master Slave D Flip Flop, and the functionality is same as a Positive D Flip Flop, which is to store memory of 1-bit at the rising edge of the clock signal. The difference is that in the SRAM Cell, the clock signal is determined by the Select Chip and the Write Enable, we will use a Tristate Logic Buffer which connects to the Select Chip input meaning that Select Chip must be on for the Output to receive a result and the Write Enable is the event that triggers at the rising edge of the clock signal to enable this SRAM Cell to store either 0 or 1.

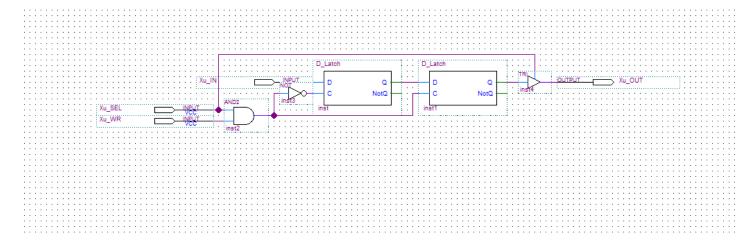


Figure 28: Block diagram of a SRAM Cell.

9.2 Simulation

In the simulation, we will test the Inputs and Outputs of a SRAM Cell.

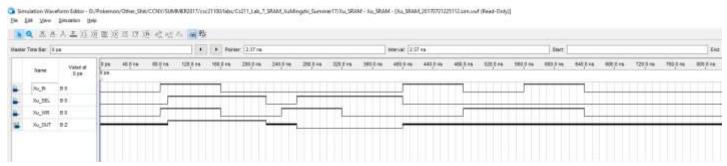


Figure 29: Simulation for SRAM Cell.

We can observe from the simulation that when the inputs IN, SEL, and WR are 0, the output will be Z because of the Tristate Logic Buffer Gate since SEL is not on, the output will not receive and results. We can also see that when the inputs IN, SEL, and WR is 1 the output will be IN. The inputs and outputs corresponds to the D Flip Flop characteristic table but the clock signal is determined by both SEL and WR.

10.16x4 SRAM

10.1 Functionality and Specification

The functionality of a 16x4 SRAM is the same as the single SRAM Cell but this time there will be 16 address locations and each address is able to store a 4-bit binary input. To build a 16x4 SRAM we can put together 64 SRAM Cells or by stacking. The idea of stacking is first we make a 16x1 by stacking 16 single SRAM Cells together which looks like this.

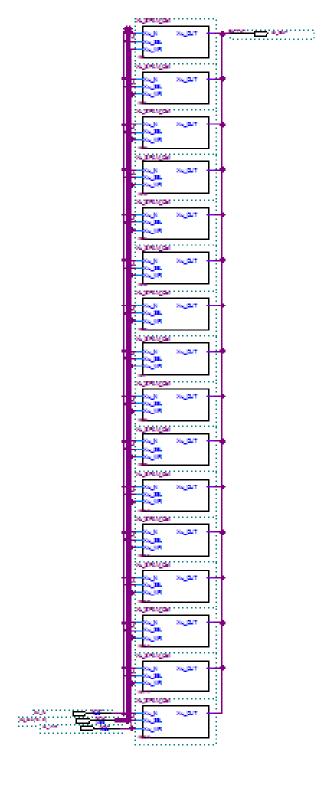


Figure 30: Block diagram of a 16x1 SRAM

The 16x1 SRAM will be able to store 1-bit of binary in 16 different address by using a 4 to 16 decoder to determine which SRAM Cell will be written and displayed. The next step into creating a 16x4 SRAM, we will make the 16x1 SRAM into a symbol and use 4 of it as components which makes up a 16x4 SRAM.

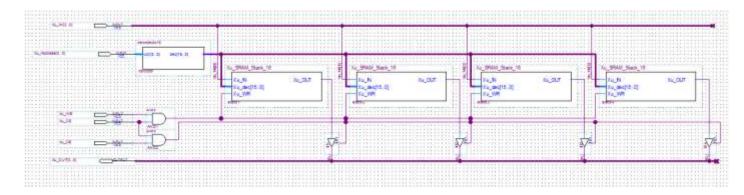


Figure 31: Block diagram of 16x4 SRAM.

As you can see in the 16x4 SRAM block diagram, there will be 4 inputs which are the 4-bit inputs that will be stored in any of the 16 addresses determined by another 4 address inputs that goes through a 4 to 16 decoder. Then everything else will be the same as the SRAM Cell where there will be a Selected Chip input CS and Write Enable input WE which determines the clock signal and there will be another input OE to display the output that connects to the Tristate Logic Buffer Gates. In the SRAM Cell, the TRI gate is connected to the CS input but this time it will be a new input OE. Next, we will want to display the output result onto the hexadecimal display in signed decimal form. To do that we will use what we have learned in the VHDL Adder Subtractor Lab where we used an inverter, negative detection, and seven-segment display to display signed decimals.

```
P P P
             → = ← =
 1
        library IEEE;
        use IEEE std_logic_1164 all;
 3
        use work.Xu_package.all;
 4
 5
6
7
      □entity sdec is
            port( x: in std_logic_vector(3 downto 0);
                   outx: out std_logic_vector(3 downto 0);
HEX3: out std_logic_vector(6 downto 0) );
 8
      end sdec;
 9
10
11
      □architecture arch of sdec is
12
            signal Z, cin: std_logic;
signal x_not, x_actual, b: std_logic_vector(3 downto 0);
13
14
15
16
17
18
      begin
                b <= "0000";
                cin <= '1';
                x_not <= not x;
                Compare0: Compare port map( x, Z );
19
                Invert0: Xu_Adder port map( cin, x_not, b, x_actual );
MUX0: Xu_MUX4 port map( x, x_actual, Z, outx );
20
21
                disNeg0: disNeg port map( Z, HEX3 );
22
        end arch;
```

Figure 32: VHDL code to display signed decimal.

In the VHDL code, I've used component Compare which is used for negative detection and the Xu_Adder component which inverts the binary input and it will go through a 2 to 1 multiplexer to determine which input to use. If it is greater than 7 it will use the inverted inputs else it will use the normal inputs. The disNeg component is used to display the negative sign on the board determined by the Compare component.

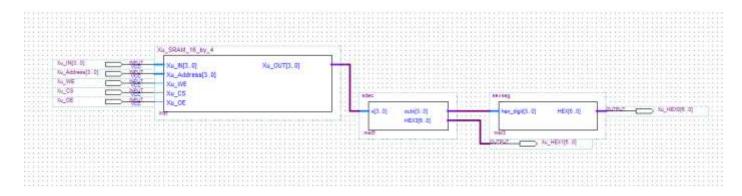


Figure 33: Block diagram for 16x4 SRAM Display in signed decimal.

10.2 Simulation



Figure 34: Simulation for 16x4 SRAM display.

In the simulation, we will assign signed decimal inputs from -8 to 7 each to one of the 16 addresses, and we can see that HEX1 which is the negative sign display is on when it is a negative input and the simulation corresponds to what we have done in the previous lab of VHDL Adder Subtractor when we needed to display signed decimal on the seven segment displays.

10.3 Demonstration

The PIN assignment of the inputs and outputs on the DE1-SoC Board.

Xu_IN[0] is assigned to SW[0] which is PIN_AB12
Xu_IN[1] is assigned to SW[1] which is PIN_AC12
Xu_IN[2] is assigned to SW[2] which is PIN_AF9
Xu_IN[3] is assigned to SW[3] which is PIN_AF10
Xu_Address[0] is assigned to SW[4] which is PIN_AD11
Xu_Address[1] is assigned to SW[5] which is PIN_AD12
Xu_Address[2] is assigned to SW[6] which is PIN_AE11
Xu_Address[3] is assigned to SW[7] which is PIN_AC9
Xu_WE is assigned to SW[8] which is PIN_AD10
Xu_CS is assigned to SW[9] which is PIN_AE12
Xu_OE is assigned to KEY[0] which is PIN_AA14

Xu_HEX0[0] is assigned to PIN_AE26
Xu_HEX0[1] is assigned to PIN_AE27
Xu_HEX0[2] is assigned to PIN_AE28
Xu_HEX0[3] is assigned to PIN_AG27
Xu_HEX0[4] is assigned to PIN_AF28
Xu_HEX0[5] is assigned to PIN_AG28
Xu_HEX0[6] is assigned to PIN_AH28
Xu_HEX1[0] is assigned to PIN_AH28
Xu_HEX1[1] is assigned to PIN_AH29
Xu_HEX1[2] is assigned to PIN_AH30
Xu_HEX1[3] is assigned to PIN_AG30
Xu_HEX1[4] is assigned to PIN_AF29
Xu_HEX1[5] is assigned to PIN_AF30
Xu_HEX1[6] is assigned to PIN_AF30
Xu_HEX1[6] is assigned to PIN_AF30

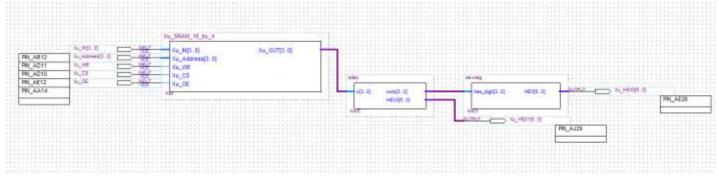


Figure 35: Block diagram of 16x4 SRAM with PIN assignments.

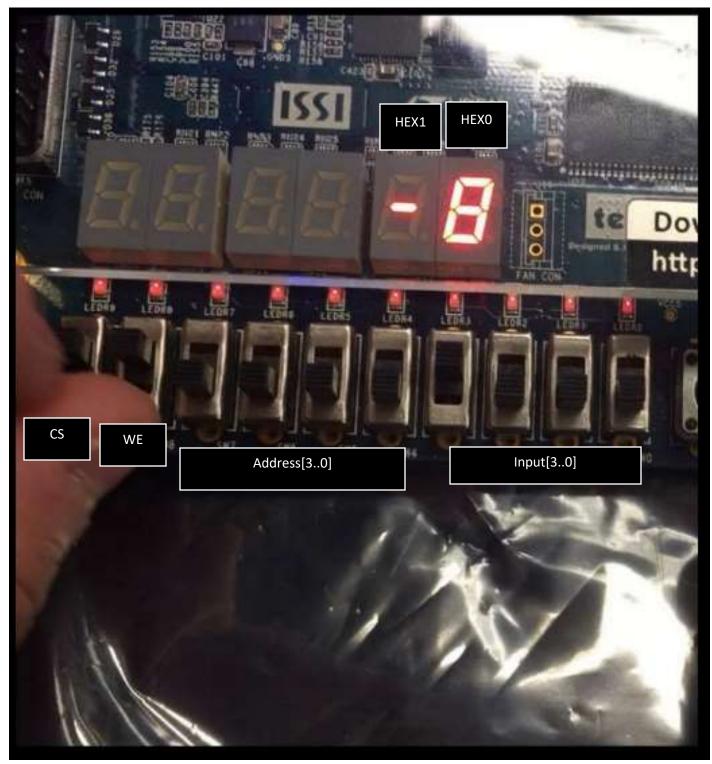
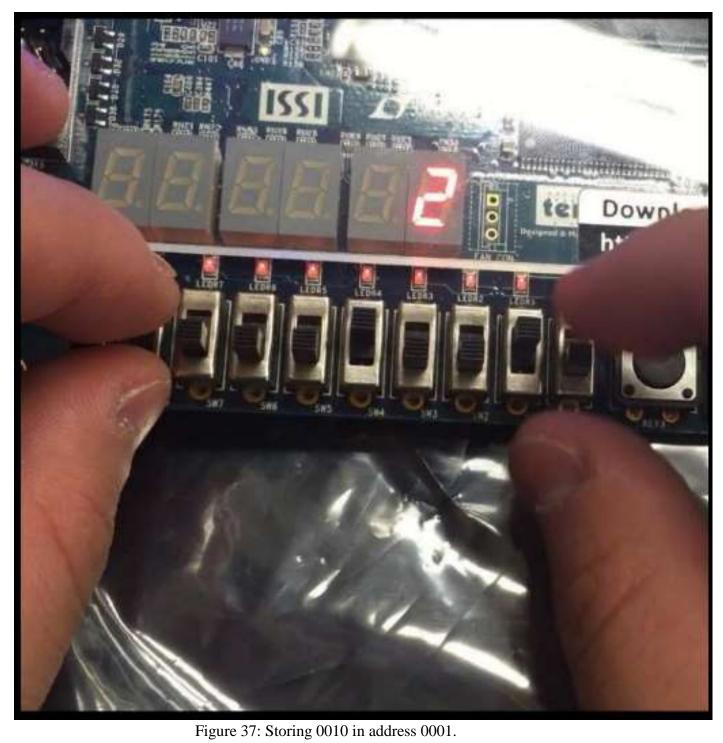


Figure 36: Storing 1000 in address 0000.



11.16x32 SRAM

11.1 Functionality and Specification

The functionality of a 16x32 SRAM has the same ideas as the SRAM Cell and the 16x4 SRAM, but this time it has 16x32 storage which can store 512-bits. There will be 16 address locations and each address is able to store 32-bits. To do this, we will use the 16x4 SRAM we just created and make it into a symbol and use 8 of the symbols as components which makes up to be the 16x32 SRAM.

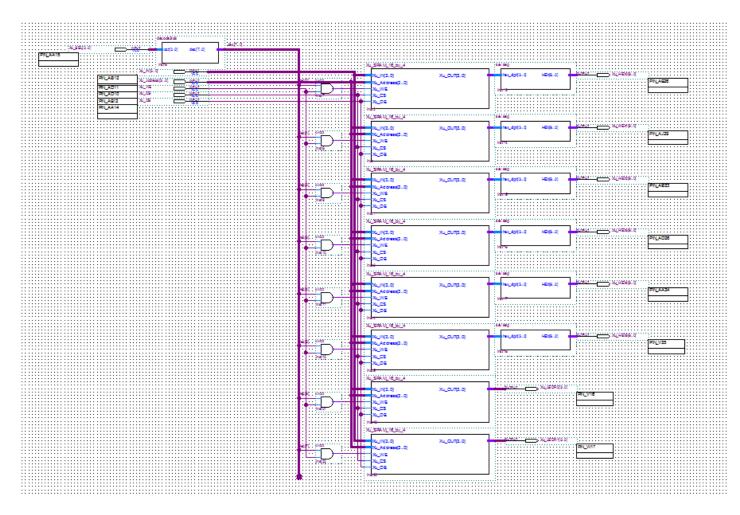


Figure 38: Block diagram of 16x32 SRAM.

The idea is same as 16x4 SRAM but there aren't enough switches to have a 32 inputs, so therefore I've made a selector using the last three KEY components on the board as SELECTOR to determine which one of the eight position of a 32-bit input it'll be writing using only 4 inputs. Therefore, I will need a 3 to 8 decoder which functions the same as how the addresses uses a 4 to 16 decoder to determine which address location it is being written to but the 3 to 8 decoder determines which 4 of the 32 position it will be written to. Since there are only 6 seven segment displays and we are displaying the result in hexadecimal form which means the seven segment displays can only display up to 24-bits. Therefore, I've used 8 LEDR to store the last 8-bits of the 32-bit inputs.

11.2 Simulation



Figure 39: Simulation for 16x32 SRAM.

In the simulation, I will be storing the binary input of 0010 which is 2 in hexadecimal to all 8 positions of display in one address. We can observe from the simulation that when we finish writing to all 8-different position of the display, it'll display 2 on all 6 seven segment display and 0010 on the LEDR for the 7th and 8th display positions.

11.3 Demonstration

The PIN assignment of the inputs and outputs on the DE1-SoC Board.

Xu_IN[0] is assigned to SW[0] which is PIN_AB12 Xu_IN[1] is assigned to SW[1] which is PIN_AC12 Xu_IN[2] is assigned to SW[2] which is PIN_AF9 Xu_IN[3] is assigned to SW[3] which is PIN_AF10 Xu_Address[0] is assigned to SW[4] which is PIN_AD11 Xu_Address[1] is assigned to SW[5] which is PIN_AD12 Xu_Address[2] is assigned to SW[6] which is PIN_AE11 Xu_Address[3] is assigned to SW[7] which is PIN_AC9 Xu_WE is assigned to SW[8] which is PIN_AD10 Xu_CS is assigned to SW[9] which is PIN_AE12 Xu_OE is assigned to KEY[0] which is PIN_AA14 Xu_SEL[0] is assigned to KEY[1] which is PIN_AA15 Xu_SEL[1] is assigned to KEY[2] which is PIN_W15 Xu_SEL[2] is assigned to KEY[3] which is PIN_Y16 Xu_HEX0[0] is assigned to PIN_AE26 Xu_HEX0[1] is assigned to PIN_AE27 Xu_HEX0[2] is assigned to PIN_AE28 Xu_HEX0[3] is assigned to PIN_AG27 Xu_HEX0[4] is assigned to PIN_AF28 Xu_HEX0[5] is assigned to PIN_AG28 Xu_HEX0[6] is assigned to PIN_AH28 Xu_HEX1[0] is assigned to PIN_AJ29 Xu_HEX1[1] is assigned to PIN_AH29 Xu_HEX1[2] is assigned to PIN_AH30 Xu_HEX1[3] is assigned to PIN_AG30

Xu_HEX1[4] is assigned to PIN_AF29

Xu_HEX1[5] is assigned to PIN_AF30
Xu_HEX1[6] is assigned to PIN_AD27
Xu_HEX2[0] is assigned to PIN_AB23
Xu_HEX2[1] is assigned to PIN_AE29
Xu_HEX2[2] is assigned to PIN_AD29
Xu_HEX2[3] is assigned to PIN_AC28
Xu_HEX2[4] is assigned to PIN_AD30
Xu_HEX2[5] is assigned to PIN_AC29
Xu_HEX2[6] is assigned to PIN_AC30
Xu_HEX3[0] is assigned to PIN_AD26
Xu_HEX3[1] is assigned to PIN_AC27
Xu_HEX3[2] is assigned to PIN_AD25
Xu_HEX3[3] is assigned to PIN_AC25
Xu_HEX3[4] is assigned to PIN_AB28
Xu_HEX3[5] is assigned to PIN_AB25
Xu_HEX3[6] is assigned to PIN_AB22
Xu_HEX4[0] is assigned to PIN_AA24
Xu_HEX4[1] is assigned to PIN_Y23
Xu_HEX4[2] is assigned to PIN_Y24
Xu_HEX4[3] is assigned to PIN_W22
Xu_HEX4[4] is assigned to PIN_W24
Xu_HEX4[5] is assigned to PIN_V23
Xu_HEX4[6] is assigned to PIN_W25
Xu_HEX5[0] is assigned to PIN_V25
Xu_HEX5[1] is assigned to PIN_AA28
Xu_HEX5[2] is assigned to PIN_Y27
Xu_HEX5[3] is assigned to PIN_AB27
Xu_HEX5[4] is assigned to PIN_AB26
Xu_HEX5[5] is assigned to PIN_AA26

Xu_HEX5[6] is assigned to PIN_AA25

Xu_LEDR0[0] is assigned to PIN_V16

Xu_LEDR0[1] is assigned to PIN_W16

Xu_LEDR0[2] is assigned to PIN_V17

Xu_LEDR0[3] is assigned to PIN_V18

Xu_LEDR1[0] is assigned to PIN_W17

Xu_LEDR1[1] is assigned to PIN_W19

Xu_LEDR1[2] is assigned to PIN_Y19

Xu_LEDR1[3] is assigned to PIN_W20

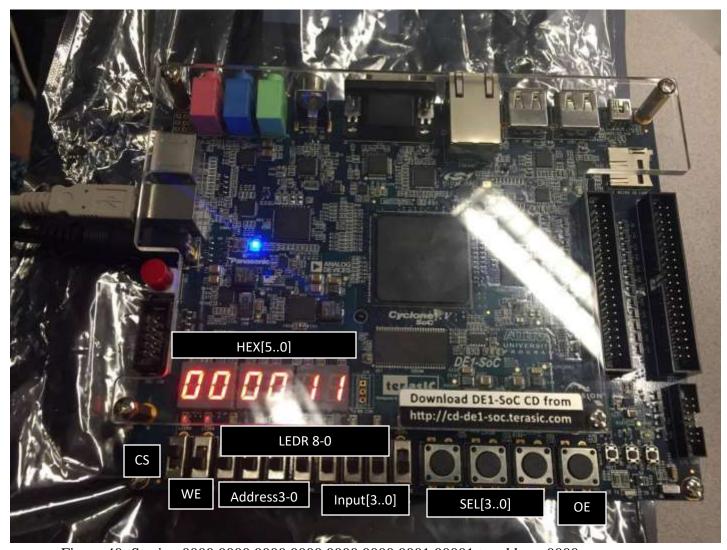


Figure 40: Storing 0000 0000 0000 0000 0000 0001 00001 to address 0000.

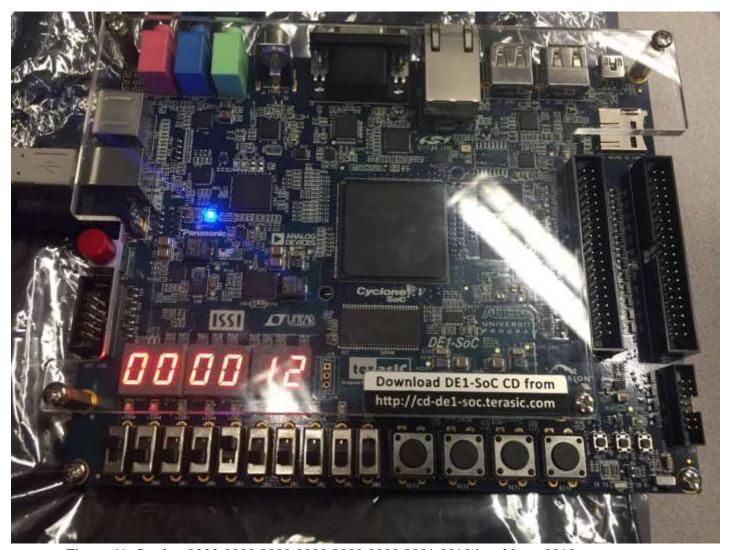


Figure 41: Storing 0000 0000 0000 0000 0000 0001 0010 in address 0010.

12. Analysis

The difference between latches and flip-flops is that they have different event triggers for the clock signal. For latches state change will occur either when clock is 0 or 1 depending if it is a positive or negative D Latch. For flip-flops state change will occur when clock signal changes from 0 to 1 or from 1 to 0. It matters because Flip-Flops can be more flexible than Latches.

We want to avoid the scenario when S and R is 1 in an SR Latch because it will lead to metastable state which means there will be no indeterminate state, it could be avoided using a D Latch since the input D will replace S and R along with a NOT gate which means S and R will always be opposite of each other so metastable state will never occur.

The differences between edge-triggered and level triggered device is the same as flip-flops and latches. Latches are level triggered device which state change will occur when the clock is either 0 or 1. Flip-Flops are edge-triggered device which state change will occur when the clock goes from 0 to 1 or from 1 to 0. The T Flip Flop is an edge-triggered device in this lab.

Flip-Flops are always required to be clocked or else it will ignore the other inputs and there won't be any outputs.

Now we will compare the results of a D Latch with Positive D Flip Flop and Negative D Flip Flop.

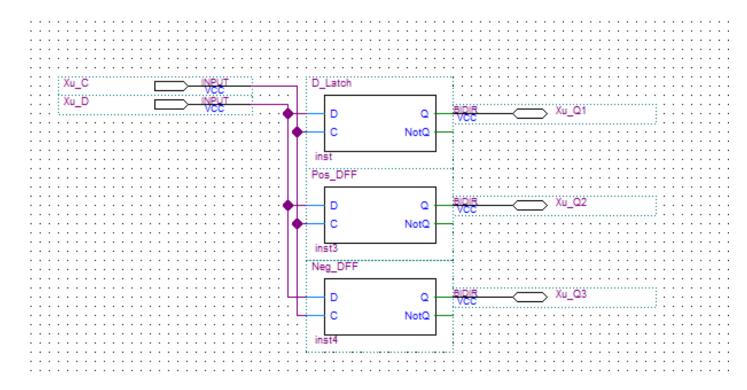


Figure : Block diagram to compare D Latch and D Flip Flops.

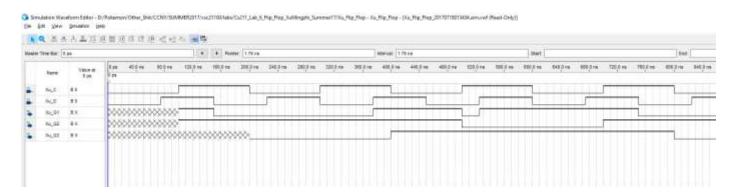


Figure : Simulation for compare D Latch and D Flip Flops.

We can observe from the simulation that for D Latch outputs 1 for Q1 when C is 1 and D is 1 and outputs 0 for Q1 when C is 1 and D is 0 and Q1 will output the previous Q1 when C is 0 and D can be either 0 or 1. The Positive and Negative Flip Flop functions the same as the D Latch but the state change occurs at the edge from 0 to 1 for Positive and from 1 to 0 for Negative.

12. Conclusion

In this lab, we learned how latches and flip-flops works as sequential devices which sends feedbacks from output back to input. We also learned the difference between latches and flip-flops which have different event trigger, for latches it is a level triggered device which will have state change occur to output when the clock signal is either 0 or 1. For flip-flops it is an edge triggered device which will have a state change occur to output when the clock signal changes from 0 to 1 or from 1 to 0. These devices will also remember previous states which means it is storing 1-bit binary information. We used the Positive D Flip Flop to construct a single cell of SRAM which allows the storage of 1-bit memory and using that one cell SRAM we can using stacking and created a 16x4 RAM which has 16 address locations and each address allows the storage of 4-bit input. We also created a 16x32 SRAM which has 16 address locations and each address allows the storage of 32-bit input.